



**PARA LIGHT ELECTRONICS CO., LTD.**  
4F, No.1, Lane 93, Chien Yi Road, Chung Ho City, Taipei, Taiwan, R.O.C.  
Tel: 886-2-2225-3733 Fax: 886-2-2225-4800  
E-mail: [para@para.com.tw](mailto:para@para.com.tw) <http://www.para.com.tw>

## DATA SHEET

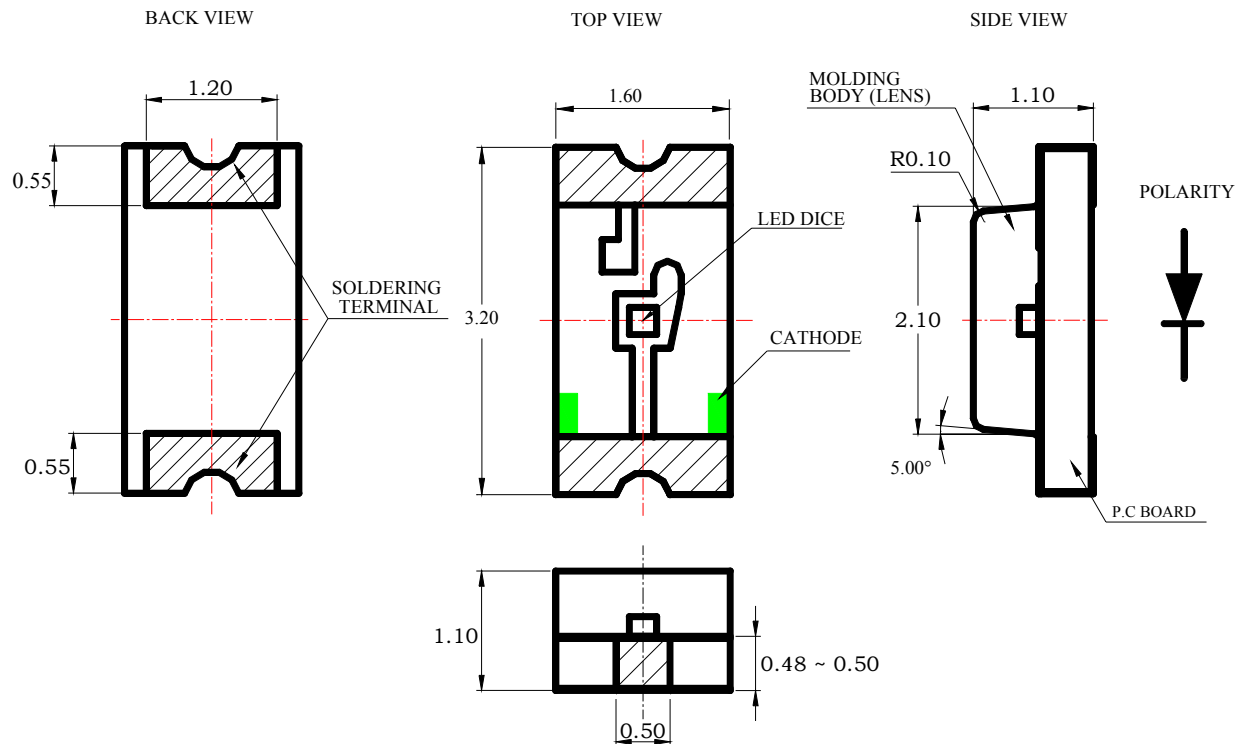
PART NO. : L-C150GCT

REV : A / 0

CUSTOMER'S APPROVAL : \_\_\_\_\_ DCC : \_\_\_\_\_

DRAWING NO. : DS-71-03-0001 DATE : 2003-12-09 PAGE 1 of 11

## ● PACKAGE OUTLINE DIMENSIONS



## Notes:

1. All dimensions are in millimeters.
2. Tolerance is  $\pm 0.1\text{mm}$  (.004") unless otherwise noted.

## ● Features

- \* Top view, wide view angle, single color Chip LED.
- \* Package in 8mm tape on 7" diameter reels.
- \* Compatible with automatic Pick & Place equipment.
- \* Compatible with Infrared and Wave soldering reflow solder processes.
- \* EIA STD package.
- \* I.C. compatible.

● **Chip Materials**

- \* Dice Material : GaP
- \* Light Color : Green
- \* Lens Color : Water Clear

● **Absolute Maximum Ratings(Ta=25°C)**

Symbol	Parameter	Rating	Unit
PD	Power Dissipation	100	mW
IPF	Peak Forward Current (1/10 Duty Cycle, 0.1ms Pulse Width)	120	mA
IF	Continuous Forward Current	25	mA
-	De-rating Linear From 25°C	0.25	mA/°C
VR	Reverse Voltage	5	V
Topr	Operating Temperature Range	-40 ~ +85	°C
Tstg	Storage Temperature Range	-40 ~ +85	°C
-	Wave Soldering Condition (Two times Max.)	260 (for 5 seconds)	°C
-	Infrared Soldering Condition (Two times MAX.)	240 (for 5 seconds)	°C

● **Electro-Optical Characteristics(Ta=25°C)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Luminous Intensity	IV	4.0	12.5		mcd	IF=20mA
Viewing Angle	2 θ 1/2		130		deg	Note 2
Peak Emission Wavelength	λ p		568		nm	Measurement @Peak
Dominant Wavelength	λ d		570		nm	IF=20mA
Spectral Line Half-Width	Δ λ		30		nm	
Forward Voltage	VF		2.1	2.6	V	IF =20mA
Reverse Current	IR			100	μ A	VR = 5V

## Notes:

1. Luminous intensity is measured with a light sensor and filter combination that proximates the CIE eye-response curve.
2.  $\theta_{1/2}$  is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
3. The dominant wavelength  $\lambda_d$  is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.
4. Caution in ESD :  
Static Electricity and surge damages the LED. It is recommend use a wrist band or anti-electrostatic glove when handling the LED. All devices, equipment and machinery must be properly grounded.
5. Major standard testing equipment by "Instrument System" Model : CAS140B Compact Array Spectrometer and "KEITHLEY" Source Meter Model : 2400.

## ● Typical Electro-Optical Characteristics Curves

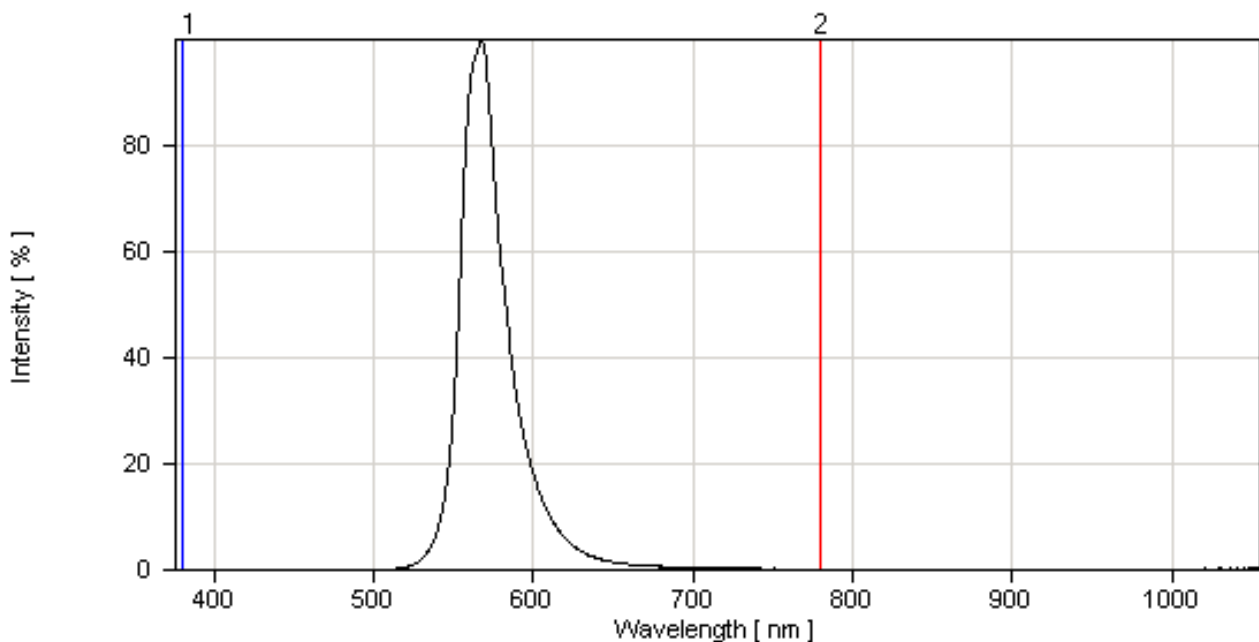


Fig.1 Relative Intensity vs. Wavelength

● Typical Electro-Optical Characteristics Curves

(25°C Ambient Temperature Unless Otherwise Noted)

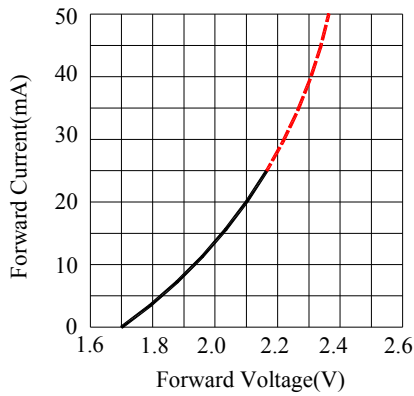


Fig.2 Forward Current vs. Forward Voltage

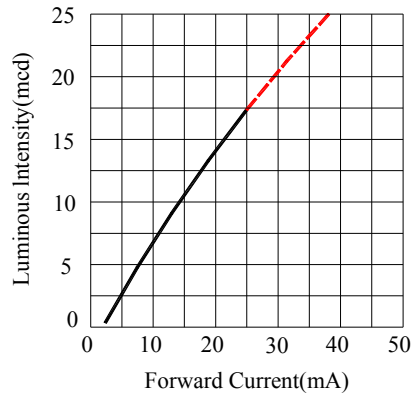


Fig.3 Luminous Intensity vs. Forward Current

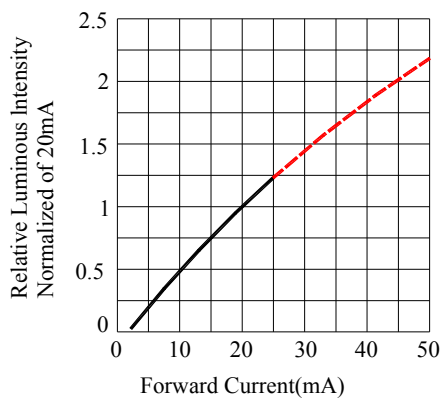


Fig.4 Relative Luminous Intensity vs. Forward Current

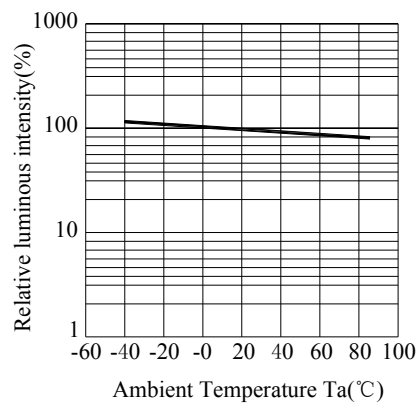


Fig.5 Luminous Intensity VS Ambient Temperature

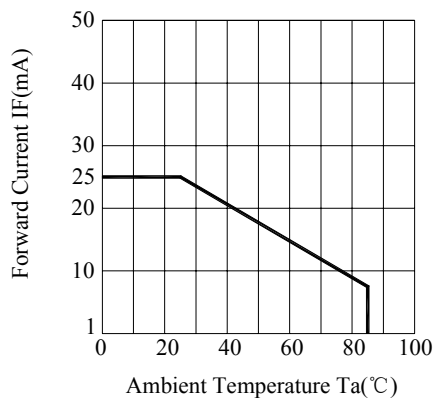


Fig.6 Forward Current Derating Curve

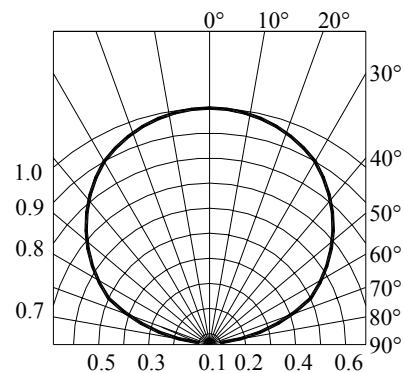


Fig.7 Forward Current Derating Curve

● Label Explanation

BATCH: L1 B9 AC

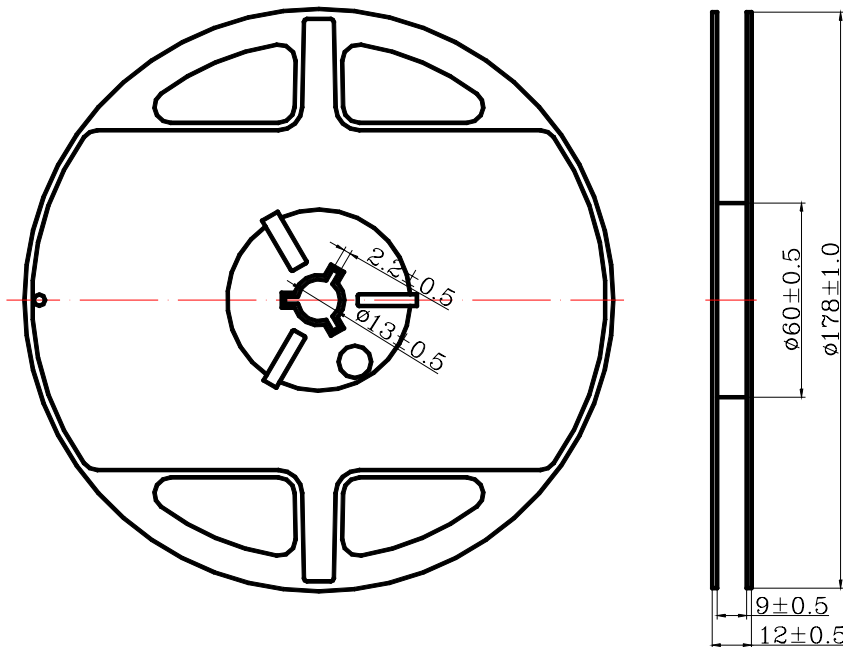
L1: Luminous Intensity Code

B9: Forward Voltage Code

AC: Dom Wavelength Code



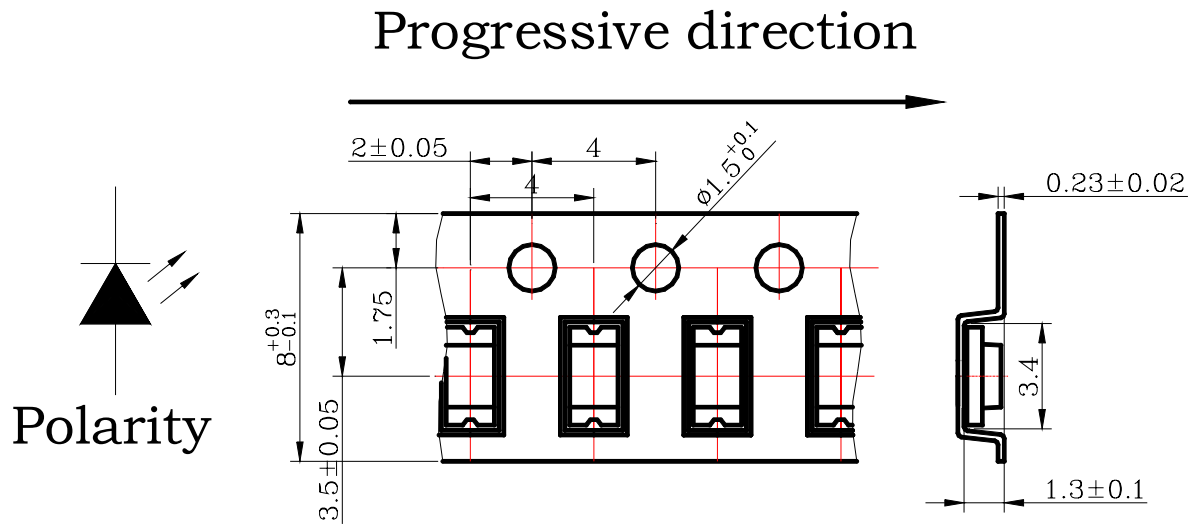
● Reel Dimensions



Notes:

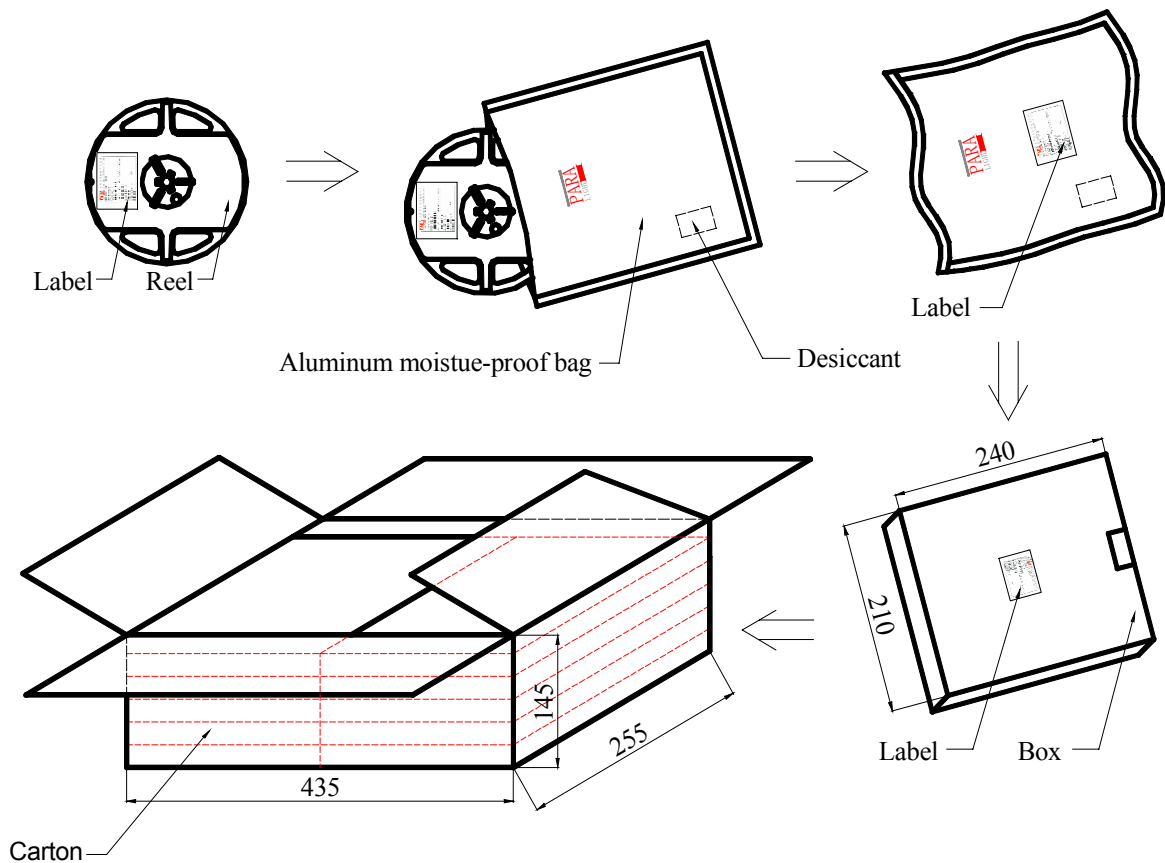
1. Taping Quantity : 3000PCS
2. The tolerances unless mentioned is  $\pm 0.1\text{mm}$ , Angle  $\pm 0.5^\circ$  , Unit : mm.

● Package Dimensions Of Tape And Reel



Notes: All dimensions are in millimeters.

Moisture Resistant Packaging

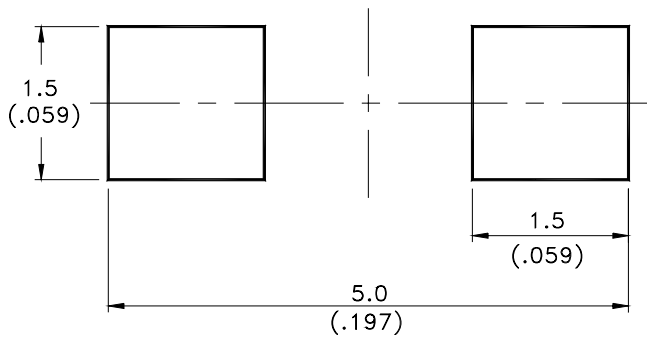


Notes : One reel in a bag, one bag in a inner box, ten inner boxes in a carton.

● Cleaning

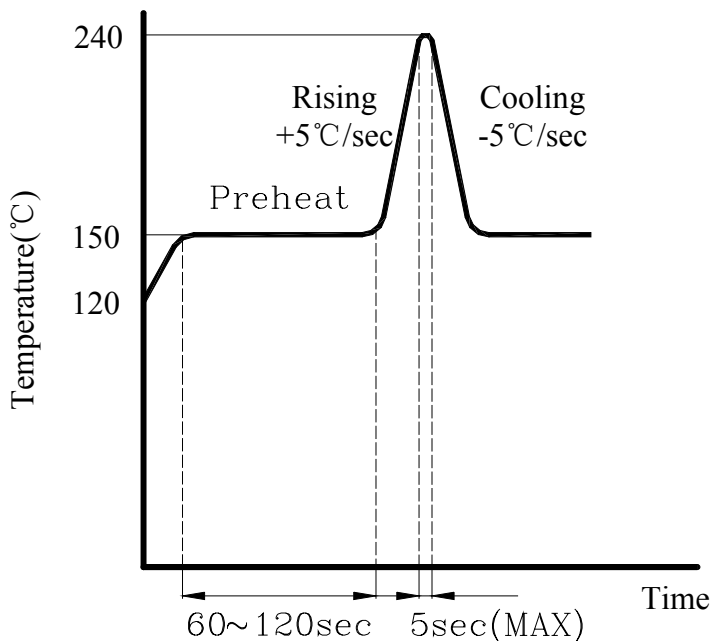
- \* If cleaning is required , use the following solutions for less than 1 minute and less than 40°C.
- \* Appropriate chemicals: Ethyl alcohol and isopropyl alcohol.
- \* Effect of ultrasonic cleaning on the LED resin body differs depending on such factors as the oscillator output, size of PCB and LED mounting method. The use of ultrasonic cleaning should be enforced at proper output after confirming there is no problem.

● Suggest Soldering Pad Dimensions



Direction of PWB camber  
and go to reflow furnace

● Suggest IR Reflow Soldering Profile Condition:





**● Bin Code List**

Luminous Intensity(IV), Unit:mcd@20mA		
Bin Code	Min	Max
J	4.0	8.0
K	6.30	12.5
L	10.0	20.0
M	16.0	32.0

Including test tolerance

**● CAUTIONS****1.Application Limitation :**

The LED's described here are intended to be used for ordinary electronic equipment (such as office equipment, communication equipment and household application).Consult PARA's sales in advance for information on application in which exceptional quality and reliability are required, particularly when the failure or malfunction of the LED's may directly jeopardize life or health (such as airplanes, automobiles, traffic control equipment, life support system and safety devices).

**2.Storage :**

Before opening the package :

The LEDs should be kept at 30°C or less and 85%RH or less. The LEDs should be used within a year.

After opening the package :

The LEDs should be kept at 30°C or less and 70%RH or less. The LEDs should be soldered within 168 hours(7 days) after opening the package.

Please avoid rapid transitions in ambient temperature in high humidity environments where condensation may occur.

**3.Soldering**

Do not apply any stress to the lead frame during soldering while the LED is at high temperature.

Recommended soldering condition.

Reflow Soldering :

Pre-heat 120~150°C, 120sec. MAX., Peak temperature : 240°C Max. Soldering time : 10 sec Max.

Soldering Iron : (Not recommended)

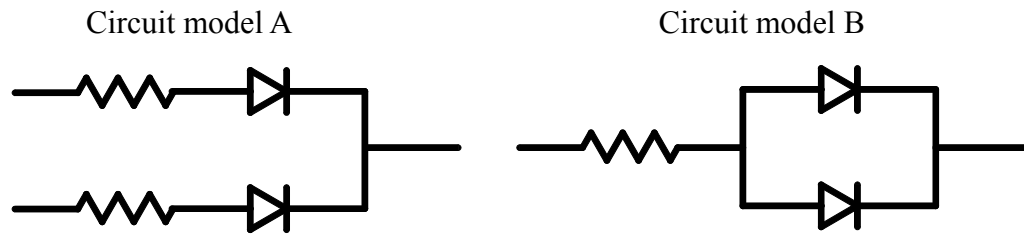
Temperature 300°C Max., Soldering time : 3 sec. Max.(one time only), power dissipation of iron :

20W Max. use SN60 solder of solder with silver content and don't to touch LED lens when soldering.

Wave soldering :

Pre-heat 100°C Max, Pre-heat time 60 sec. Max, Solder wave 260°C Max, Soldering time 5 sec. Max. preformed consecutively cooling process is required between 1<sup>st</sup> and 2<sup>nd</sup> soldering processes.

### 4. Drive Method



(A) Recommended circuit.

(B) The difference of brightness between LED's could be found due to the Vf-If characteristics of LED.

### 5. Reliability Test

Classification	Test Item	Test Condition	Reference Standard
Endurance Test	Operation Life	Ta= Under Room Temperature As Per Data Sheet Maximum Rating *Test Time= 1000HRS (-24HRS,+72HRS)*@20mA.	MIL-STD-750D:1026 (1995) MIL-STD-883D:1005 (1991) JIS C 7021:B-1 (1982)
	High Temperature High Humidity Storage	IR-Reflow In-Board, 2 Times Ta= 65±5°C, RH= 90~95% *Test Time= 1000HRS±2HRS	MIL-STD-202F:103B(1980) JIS C 7021:B-11(1982)
	High Temperature Storage	Ta= 105±5°C Test Time= 1000HRS (-24HRS,72HRS)	MIL-STD-883D:1008 (1991) JIS C 7021:B-10 (1982)
	Low Temperature Storage	Ta= -55±5°C *Test Time=1000HRS (-24HRS,72H RS)	JIS C 7021:B-12 (1982)
Environmental Test	Temperature Cycling	105±5°C      -55±5°C 10mins      10mins      100 Cycles	MIL-STD-202F:107D (1980) MIL-STD-750D:1051(1995) MIL-STD-883D:1010 (1991) JIS C 7021:A-4(1982)
	Thermal Shock	IR-Reflow In-Board, 2 Times 105±5°C      -55°C±5°C 10mins      10mins      100 Cycles	MIL-STD-202F:107D(1980) MIL-STD-750D:1051(1995) MIL-STD-883D:1011 (1991)
	Solder Resistance	Tsol= 260 ± 5°C Dwell Time= 10 ± 1sec	MIL-STD-202F:210A(1980) MIL-STD-750D:2031(1995) JIS C 7021:A-1(1982)
	Solder ability	Tsol= 235 ± 5°C Immersion time 2±0.5 sec Immersion rate 25±2.5 mm/sec Coverage ≥95% of the dipped surface	MIL-STD-202F:208D(1980) MIL-STD-750D:2026(1995) MIL-STD-883D:2003(1991) IEC 68 Part 2-20 JIS C 7021:A-2(1982)

### 6. Others:

The appearance and specifications of the product may be modified for improvement without notice.

● PART NO. SYSTEM :

L - C 1 5 0 X C X X - X X X X

XXXX : Special specification for customer

T : Taping for 7 inch reel  
 TC : Taping for 13 inch reel  
 TH : IV half binning  
 TP : Wavelength binning

Lens color  
 C : Water Clear  
 W : White Diffused  
 T : Color Transparent  
 D : Color Diffused

G : Gap 570nm Green  
 Y : GaAsp 585 nm Yellow  
 E : GaAsp 620 nm Orange  
 SR : GaAlAs 634 nm Red  
 KG : AllnGap 570nm Super Green  
 KY : AllnGap 590nm Super Yellow  
 KF : AllnGap 605nm Super Amber  
 KR : AllnGap 630 nm Super Red  
 LB : InGaN 470nm Blue  
 LG: InGaN 525nm Green

0 : Single chip  
 1/2 : Super thin single chip  
 5/6 : Dual chip  
 F : Three chip(Full color)

150 : 1206 1.1T Type  
 170 : 0805 0.8T Type  
 191 : 0603 0.6T Type  
 192 : 0603 0.4T Type  
 110 : 1206 1.0T Type

C : Top View Type  
 S : Side View Type